





#### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

- Dual P-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Up To 3KV
- Lead Free By Design/RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

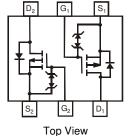
- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (approximate)

**SOT563** 









Top View

**Bottom View** 

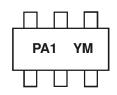
Ordering Information (Note 3)

Part Number	Case	Packaging
DMG1023UV-7	SOT563	3,000 / Tape & Reel
DMG1023UV-13	SOT563	10,000 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.

2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com

### **Marking Information**



PA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009) M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	20	10	2011	2012	2013	2014	20	15	2016	2017
Code	V	W	)	X	Υ	Z	Α	В	(	0	D	E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

<sup>3.</sup> For packaging details, go to our website at http://www.diodes.com.



### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	$V_{DSS}$	-20	V		
Gate-Source Voltage	$V_{GSS}$	±6	V		
Continuous Drain Current (Note 4) V <sub>GS</sub> = -4.5V	Steady State	$T_A = 25$ °C $T_A = 85$ °C	I <sub>D</sub>	-1.03 -0.68	Α
Pulsed Drain Current (Note 5)	I <sub>DM</sub>	-3	Α		

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P <sub>D</sub>	530	mW
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = 25°C (Note 4)	R <sub>0JA</sub>	235	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

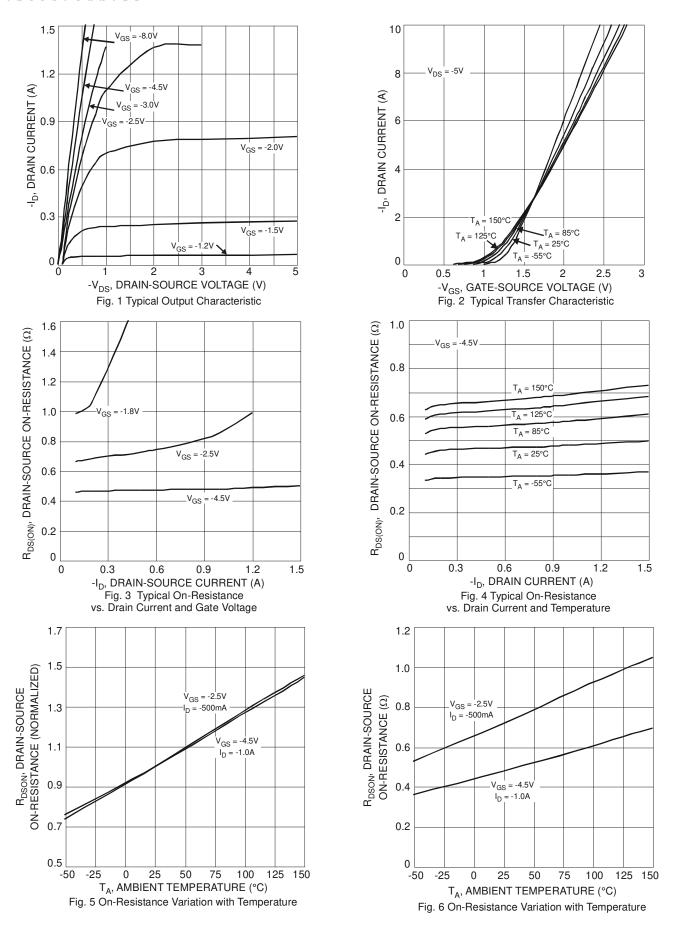
### Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	-	-	V	$V_{GS} = 0V$ , $I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	-	-	±2.0	μΑ	$V_{GS} = \pm 4.5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.5	-	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
			0.5	0.75		$V_{GS} = -4.5V, I_D = -430mA$	
			0.7	1.05	Ω	$V_{GS} = -2.5V, I_D = -300mA$	
Static Drain-Source On-Resistance	R <sub>DS</sub> (ON)	-	1.0	1.5		$V_{GS} = -1.8V, I_D = -150mA$	
	, ,		-	20		$V_{GS} = -1.7V, I_D = -100mA$	
			-	25		V <sub>GS</sub> = -1.5V, I <sub>D</sub> = -100mA	
Forward Transfer Admittance	Y <sub>fs</sub>	-	0.9	-	S	$V_{DS} = -10V, I_{D} = -250mA$	
Diode Forward Voltage	V <sub>SD</sub>		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$	
DYNAMIC CHARACTERISTICS (Note 7)						•	
Input Capacitance	C <sub>iss</sub>	-	59.76	-	pF		
Output Capacitance	Coss	-	12.07	-	pF	$V_{DS} = -16V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	6.36	-	pF	T = 1.0WHZ	
Total Gate Charge	Qq	-	622.4	-	рС	V 45V V 40V	
Gate-Source Charge	Q <sub>qs</sub>	-	100.3	-	рС	$V_{GS} = -4.5V$ , $V_{DS} = -10V$ ,	
Gate-Drain Charge	$Q_{gd}$	-	132.2	-	рС	$I_D = -250 \text{mA}$	
Turn-On Delay Time	t <sub>D(on)</sub>	-	5.1	-	ns	V 40V V 45V	
Turn-On Rise Time	t <sub>r</sub>	-	8.1	-	ns	V <sub>DD</sub> = -10V, V <sub>GS</sub> = -4.5V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	-	28.4	-	ns	$R_L = 47\Omega, R_G = 10\Omega,$ $R_D = -200 \text{mA}$	
Turn-Off Fall Time	t <sub>f</sub>	-	20.7	-	ns	71D = -20011IA	

Notes:

- Device mounted on FR-4 PCB, with minimum recommended pad layout.
  Repetitive rating, pulse width limited by junction temperature.
  Short duration pulse test used to minimize self-heating effect.
  Guaranteed by design. Not subject to production testing.







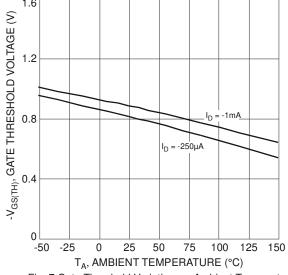
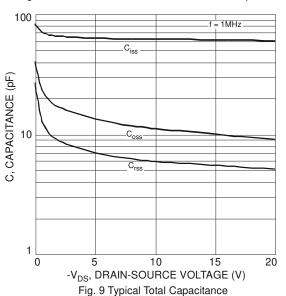
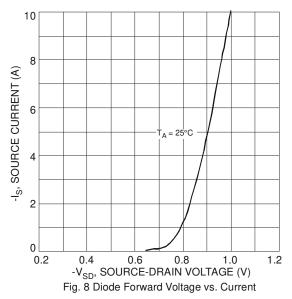


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





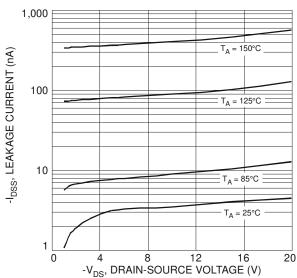


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

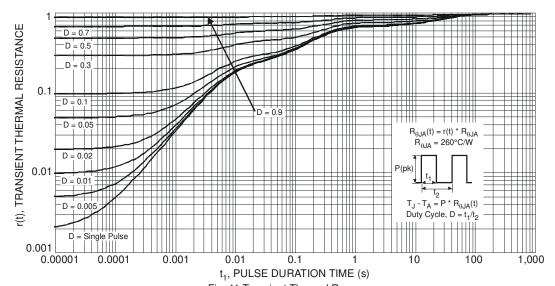
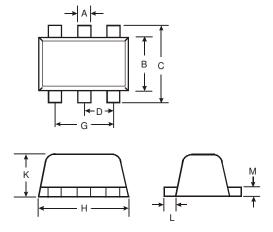


Fig. 11 Transient Thermal Response

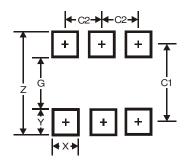


# **Package Outline Dimensions**



SOT563							
Dim	Min	Max	Тур				
Α	0.15	0.30	0.20				
В	1.10	1.25	1.20				
С	1.55	1.70	1.60				
D	-	-	0.50				
G	0.90	1.10	1.00				
Н	1.50	1.70	1.60				
K	0.55	0.60	0.60				
L	0.10	0.30	0.20				
М	0.10	0.18	0.11				
All Dimensions in mm							

## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Υ	0.5
C1	1.7
C2	0.5



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